

SPECIFICATION

CUSTOMER PART NO. : XEA-078A01-DI9509-G030

PRODUCT NO. : TCXD078IBLMT-98

VERSION : Ver 1.1

ISSUED DATE : 2023/2/8

This module uses ROHS material

FOR CUSTOMER: _____

: APPROVAL FOR SPECIFICATION

: APPROVAL FOR SAMPLE

DATE	APPROVED BY

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2. General Description and Features

The 7.8 inch Module named TCXD078IBLMT-98 is a-Si TFT-LCD module, which is the type of transmissive. It is consisted of TFT-LCD Panel, Driver IC, FPC, Back-Light and Touch Panel unit. Features of this product are listed in the following table.

NO	Item	Contents	Unit
(1)	Module Outline(DTC)	83.35(H)*218.35(V)*8.45(T)	mm
(2)	LCD Active area	59.40(H)*190.08(V)	mm
(3)	Dot Number	400*3(RGB)*1280	/
(4)	Dot size	0.0495(H) ×0.1485 (V)	mm
(5)	LCD type	TFT Transmissive	/
(6)	Display Mode	Normally Black(IPS)	/
(7)	Display Color	16.7M	/
(8)	Viewing direction	ALL	O'clock
(9)	Backlight Type	24 Chip	/
(10)	Power Supply	3.3(TYP)	V
(11)	Interface	FPC 0.5mm_Pitch 40pin	/
(12)	Interface type	MIPI interface	/
(13)	With /Without TSP	With CTP	/
(14)	Driver IC	TFT:OTA7290B-C/C1/C2 CTP:SIS9509	/

4. Interface Pin Connection

FPC Connector is used for the module electronics interface. The recommended model is FPC0.5G-WTX-40P.

No.	Symbol	I/O	Function
1	LEDA	P	Led anode
2	LEDA	P	Led anode
3	LEDA	P	Led anode
4	NC	-	No connection
5	LEDK	P	LED Cathode
6	LEDK	P	LED Cathode
7	LEDK	P	LED Cathode
8	LEDK	P	LED Cathode
9	GND	P	Ground
10	GND	P	Ground
11	D3N	I	MIPI data Input
12	D3P	I	MIPI data Input
13	GND	P	Ground
14	D2N	I	MIPI data Input
15	D2P	I	MIPI data Input
16	GND	P	Ground
17	CLKN	I	MIPI data Input
18	CLKP	I	MIPI data Input
19	GND	P	Ground
20	D1N	I	MIPI data Input
21	D1P	I	MIPI data Input
22	GND	P	Ground
23	D0N	I/O	MIPI data Input
24	D0P	I/O	MIPI data Input
25	GND	P	Ground

26	ID1(NC)	-	No connection
27	RESET	I	Global reset pin , active Low. High voltage level : VCI
28	NC	-	No connection
29	IOVCC	P	I/O voltage. Not used within display and can be left unconnected
30	VCI	P	A power supply for DC/DC circuit.
31	TPGND	P	TP Ground
32	SCL	I/O	TP I2C:serial clock
33	SDA	I/O	TP I2C:serial data
34	TPVDD	P	TP Power Supply
35	TPRST	I	TP System reset signal input, active low
36	INT	O	TP Indicate coordinate ready
37	TPGND	P	TP Ground
38	GND	P	Ground
39	GND	P	Ground
40	GND	P	Ground

5. Maximum Rating

Item	Symbol	Rating	Unit
Operating temperature	Top	-20 to 70	°C
Storage temperature	Tst	-30 to 80	°C
Power input	VCI	-0.5~ 4	V
Operating Humidity	HOP	10 to 90	%RH
Storage Humidity	HST	10 to 90	%RH

6. Electrical Characteristics

Item		Symbol	Condition	Min.	Typ.	Max.	Unit
Power supply		VCI	-	2.7	3.3	3.6	V
VCI input voltage level	H level	V_{IH1}	-	0.7*VCI	-	VCI	V
	L level	V_{IL1}		0	-	0.3*VCI	V

7. Backlight Characteristics

Item	syb	Min	Typ	Max	Unit	Condition
Voltage	Vf	16.2	18	19.8	V	IF=100mA
Number of LED	-	24			pcs	-
Power Consumption	PWF	-	1800	-	mW	-
LED life-span	-	(25000)	-	-	Hrs	-

8. Touch Panel characteristics

Item	Symbol	Condition
Structure	G+G	-
Interface	IIC	-
Transmission	≥85%	Haze meter
Channels	TX:11 RX:33	-
Surface Hardness	6H	Pencil hardness tester
Touch Count Max	10	-

9. Timing Characteristics

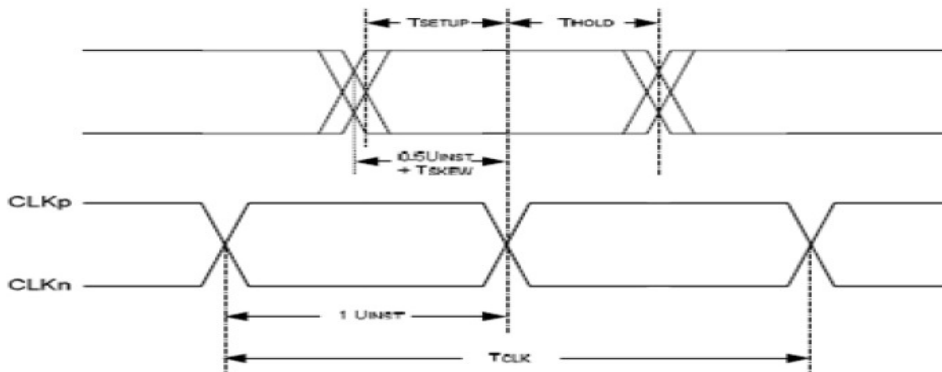
9.1 MIPI AC characteristics

HS Receiver AC Timing Characteristics

Parameter	Symbol	Rating			Unit	Note
		Min	Typ	Max		
Bandwidth per lane	-	-	-	1000	Mbps	Bandwidth selected by register 'speedup' Speedup=0 → Max=550Mbps Speedup=1 → Max=1000Mbps
Operation frequency	-	-	-	500	MHz	
UI instantaneous	U_{INST}	1	-	12.5	ns	1
Data to Clock Skew	T_{skew}	-0.15	-	0.15	U_{INST}	
Inter-lane static skew	$T_{skew-lane}$	-	-	$U_{INST}/50$	U_{INST}	
Data to Clock Setup Time	T_{SETUP}	0.25	-	-	U_{INST}	2
Data to Clock Hold Time	T_{HOLD}	0.25	-	-	U_{INST}	
Common-mode interference beyond 450MHz	$\Delta V_{CMRX(HF)}$	-	-	100	mV	4
Common-mode interference 50MHz- 450MHz	$\Delta V_{CMRX(LF)}$	-50	-	50	mV	3,6
Common-mode termination	C_{CM}	-	-	60	pF	5

Note:

- (1) Total silicon and package delay budget of $0.3 \cdot U_{INST}$
- (2) Total setup and hold window for receiver of $0.3 \cdot U_{INST}$
- (3) Excluding 'static' ground shift of 50mV
- (4) $\Delta V_{CMRX(HF)}$ is the peak amplitude of a sine wave superimposed on the receiver input
- (5) For higher bit rates a 14pF capacitor will be needed to meet the common-mode return loss specification.
- (6) Voltage difference compared to the DC average common-mode potential.



LP Receiver AC Timing Characteristics

Parameter	Symbol	Rating			Unit	Note
		Min	Typ	Max		
Input pulse rejection	e_{SPIKE}	-	-	300	V-ps	1,2,3
Minimum pulse width response	$T_{\text{MIN-RX}}$	20	-	-	ns	
Peak interference amplitude	V_{INT}	-	-	200	mV	
Interference frequency	f_{INT}	450	-	-	MHz	
Logic 1 input voltage	V_{IH}	880	-	-	mV	
Logic 0 input voltage, not in ULP State	V_{IL}	-	-	550	mV	
Logic 0 input voltage, ULP State	$V_{\text{IL-ULPS}}$	-	-	300	mV	
Input Hysteresis	V_{HYST}	25	-	-	mV	
Logic 1 contention threshold	V_{HCD}	450	-	-	mV	
Logic 0 contention threshold	V_{LCD}	-	-	200	mV	

Note:

- (1) Time-voltage integration of a spike above V_{IL} when being in LP-0 state or below V_{IH} when being in LP-1state.
- (2) An impulse less than this will not change the receiver state.
- (3) In addition to the required glitch rejection, implementers shall ensure rejection of known RF-interferers.

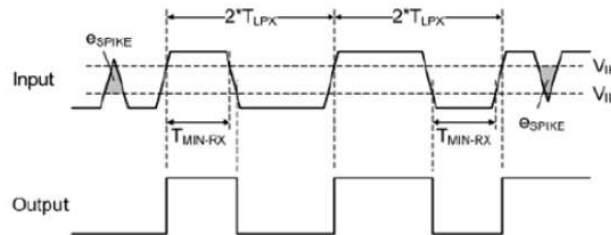
9.2 MIPI DC characteristics

(VCC=1.5V, VDD=3.3V, AVDD=12V, VSS=VSSA=0V, TA=-20 to +85°C)

Parameter	Symbol	MIN.	Typ.	MAX.	UNIT	Conditions
VDD Input low voltage level	V_{il1}	0	-	$0.3 \cdot V_{\text{DD}}$	V	For the VDD domain inputs.
VDD Input high voltage level	V_{ih1}	$0.7 \cdot V_{\text{DD}}$	-	VDD	V	For the VDD domain inputs.
VCC Input low voltage level	V_{il2}	0	-	$0.2 \cdot V_{\text{CC}}$	V	For the VCC domain inputs.
VCC Input high voltage level	V_{ih2}	$0.8 \cdot V_{\text{CC}}$	-	VCC	V	For the VCC domain inputs.
I2C Low level input voltage	V_{il3}	1.65	-	VDD	V	For SDA/SCL inputs
I2C High level input voltage	V_{ih3}	0	-	0.2	V	For SDA/SCL inputs
Input leakage current	I_{I}	-	-	+/- 1	μA	For the digital, I/O circuit (Not include the pull-up/down current)
Output high voltage level	V_{oh}	$0.8 \cdot V_{\text{DD}}$	-	-	V	For VDD domain outputs, $I_{\text{oh}} = 400\mu\text{A}$
Output low voltage level	V_{ol}	-	-	$0.2 \cdot V_{\text{DD}}$	V	For VDD domain outputs, $I_{\text{ol}} = 400\mu\text{A}$
Differential input leakage Current	I_{DIFF}	-10	-	+10	μA	For DxP, DxN, CLKP, CLKN (With steady state inputs)
Pull low/high resistor	R_{i}	100K	250K	500K	ohm	For the digital Input pin VDD=3.3, VCC=1.5
Output Voltage deviation	VOD1		± 20	± 35	mV	$V_{\text{o}} = \text{AGND}+0.2\text{V} \sim \text{AGND}+1.5\text{V}$ $V_{\text{o}} = \text{HAVDD}-0.2\text{V} \sim \text{HAVDD}-1.5\text{V}$ $V_{\text{o}} = \text{HAVDD}+0.2\text{V} \sim \text{HAVDD}+1.5\text{V}$
Output Voltage deviation	VOD2		± 15	± 20	mV	$V_{\text{o}} = \text{AGND}+0.2\text{V} \sim \text{AGND}+1.5\text{V}$ $V_{\text{o}} = \text{AGND}+1.5\text{V} \sim \text{HAVDD}-1.5\text{V}$ $V_{\text{o}} = \text{HAVDD}+1.5\text{V} \sim \text{AVDD}-1.5\text{V}$
Output Voltage Offset between Chips	VOC			± 20		$V_{\text{o}} = \text{AGND}+1.5\text{V} \sim \text{HAVDD}-1.5\text{V}$ $V_{\text{o}} = \text{HAVDD}+1.5\text{V} \sim \text{AVDD}-1.5\text{V}$
Input level of V1 ~ V7	V_{ref1}	HAVDD+0.2	-	AVDD-0.2	V	Gamma positive voltage input
Input level of V8 ~ V14	V_{ref2}	0.2	-	HAVDD-0.2	V	Gamma negative voltage input
Dynamic Range of Output	V_{dr}	0.2	-	AVDD-0.2	V	S0 ~ S1802
Sinking Current of Outputs	I_{OLy}	80	-	-	μA	S0 ~ S1802
Driving Current of Outputs	I_{OHy}	80	-	-	μA	S0 ~ S1802
Digital Operation current	I_{dd}	-	TBD	-	mA	
Digital Stand-by current	I_{st1}	-	TBD	-	μA	
Analog Operation current	I_{dda}	-	TBD	-	mA	
Analog Stand-by current	I_{st2}	-	TBD	-	μA	

LP Receiver DC Specification

Parameter	Symbol	Rating			Unit	Note
		Min	Typ	Max		
Logic 1 input voltage	V_{IH}	880	-	-	mV	
Logic 0 input voltage, not in ULP State	V_{IL}	-	-	550	mV	
Input hysteresis	V_{HYST}	25	-	-	mV	



Line Contention Detection

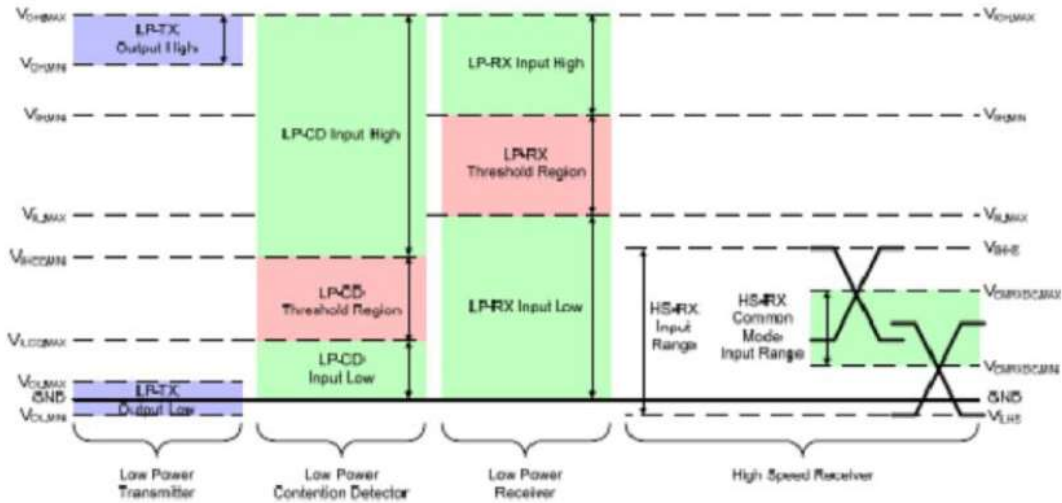
Parameter	Symbol	Rating			Unit	Note
		Min	Typ	Max		
Logic 1 contention threshold	V_{IHCD}	450	-	-	mV	
Logic 0 contention threshold	V_{ILCD}	-	-	200	mV	

HS Receiver DC Specification

Parameter	Symbol	Rating			Unit	Note
		Min	Typ	Max		
Operation Voltage	VDD	1.5-10%	1.5	1.5+10%	mV	
Differential Input Voltage	VID	70	200	260	mV	
Common Mode Voltage	$V_{CMRX(DC)}$	70	-	330	mV	
Differential Input High Threshold Voltage	VTH	-	-	70	mV	
Differential Input Low Threshold Voltage	VTL	-70	-	-	mV	
Singled-ended input high voltage	V_{IHHS}	-	-	460	mV	
Singled-ended input low voltage	V_{ILHS}	-40	-	-	mV	
Singled-ended threshold for HS termination enable	$V_{TERM-EN}$	-	-	450	mV	
Differential input impedance	Z_{ID}	80	100	125	ohm	
Pin leakage current	I_{LEAK}	-10	-	10	uA	
Common-mode interference beyond 450MHz	$\Delta V_{CMRX(HF)}$	-	-	100	mV	
Common-mode interference 50MHz - 450MHz	$\Delta V_{CMRX(LF)}$	-50	-	50	mV	
Common-mode termination	C_{CM}	-	-	60	pF	
Embedded Termination	R_T	90	100	110	ohm	2bits RT_SEL[1: 0] for termination resistor selection 00 → 200ohm 10 , 01 → 150ohm 11 → 100ohm (default) 1bit ERMEN for termination resistor enable TERMR_EN=0, termr disable R=(OPEN) TERMR_EN=1, termr enable

Note:

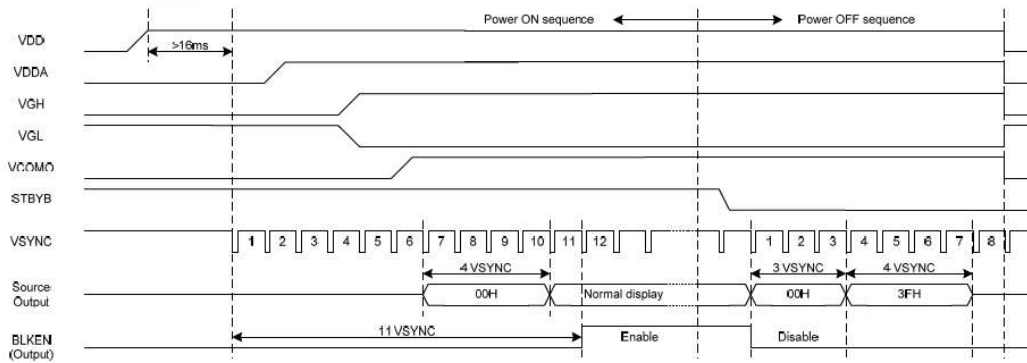
- (1) Excluding possible additional RF interference of 100mV peak sine wave beyond 450MHz.
- (2) This table value includes a ground difference of 50mV between the transmitter and the receiver, the static common-mode level tolerance and variations below 450MHz.



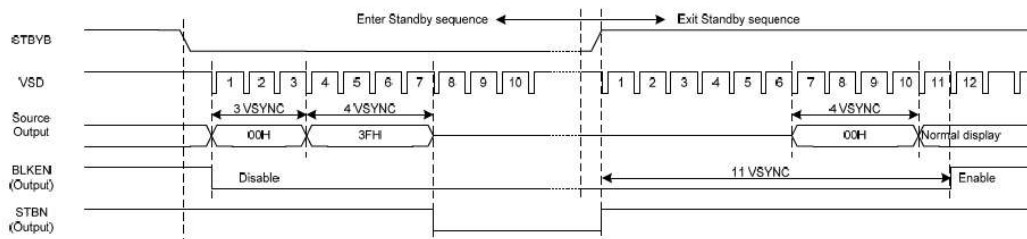
9.3 Power On/Off sequence

In order to prevent IC from power on reset fail, the rising time (T_{POR}) of the digital power supply VDD should be maintained within the given specifications. Refer to "AC Characteristics" for more detail on timing.

Power-On/Off Timing Sequence:



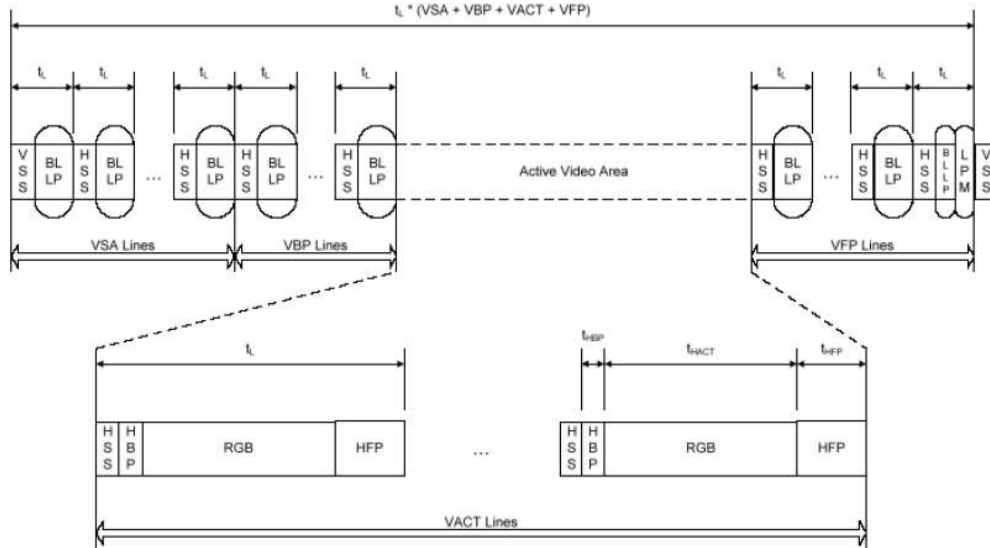
Enter and Exit Standby Mode Sequence:



9.4 MIPI Interface

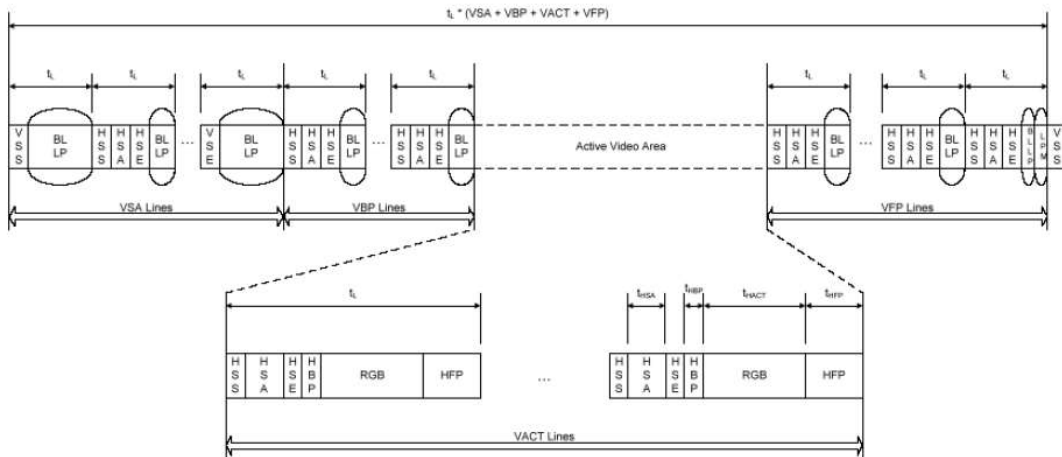
Non-Burst Mode with Sync Event

This mode is a simplification of Non-Burst Mode with Sync Pulse. Only the start of each synchronization pulse is transmitted. The peripheral may regenerate Sync as needed from each Sync Event packet received.



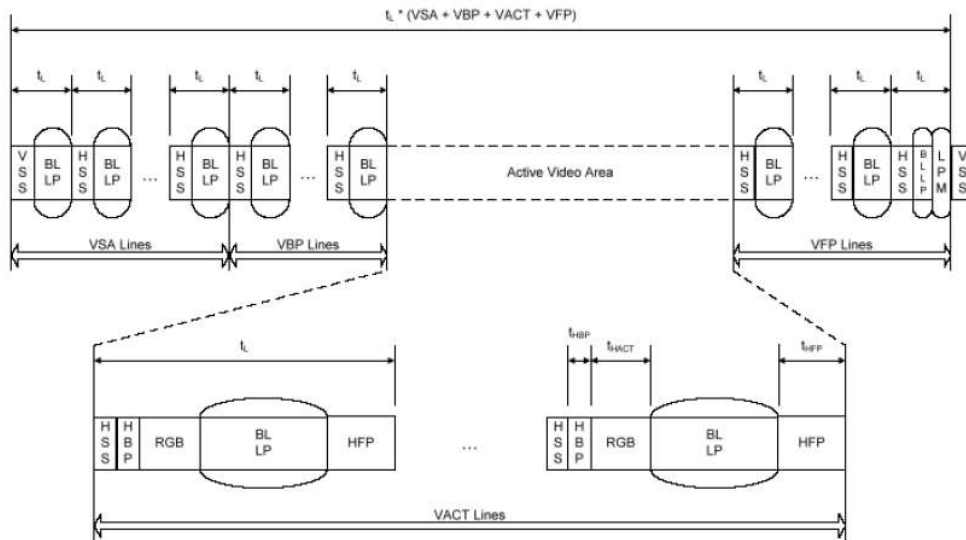
Non-Burst Mode with Sync Pulse

With this format, the goal is to accurately convey DPI-type timing over the DSI serial Link. This includes matching DPI pixel transmission rates, and width of timing events like sync pulse.



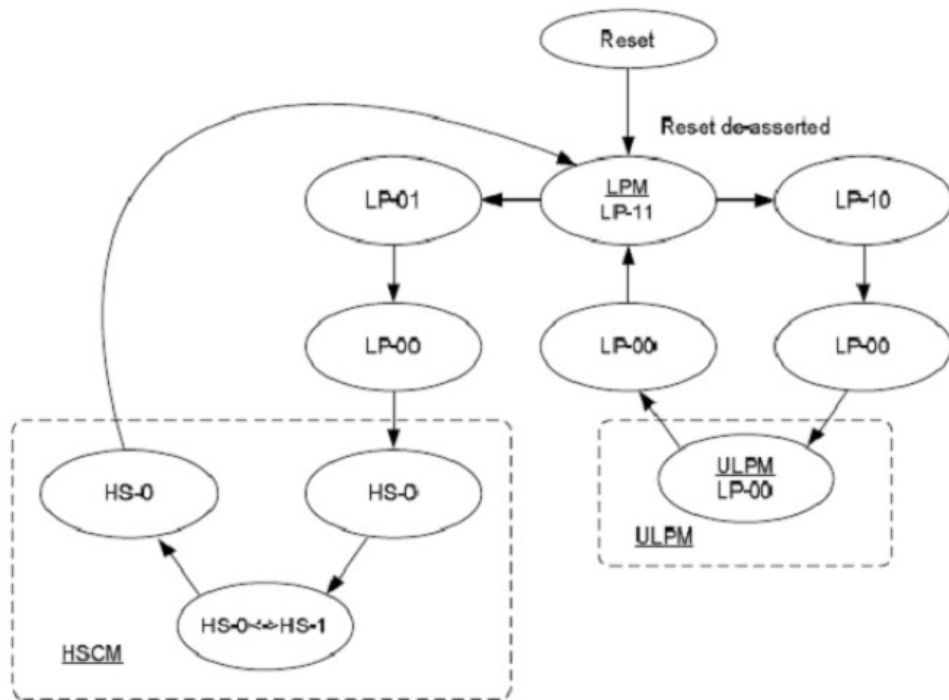
Burst Mode

In this mode, blocks of pixel data can be transferred in a shorter time using a time-compressed burst format.



Power Management

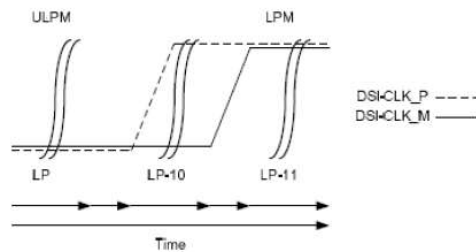
DSI-CLK_P/M can be driven into three different power modes: Low Power Mode (LPM), Ultra Low Power Mode (ULPM) and High Speed Clock Mode (HSCM). When LPM, ULPM, enter in LPM/ULPM and Leaving out HSCM case, the DSI-CLK_P/M is single end mode.



Low Power Mode (LPM)

DSI-CLK_P/M lanes are driven to the Low Power Mode (LPM), when DSI-CLK lanes are entering LP-11 state code, in three different ways:

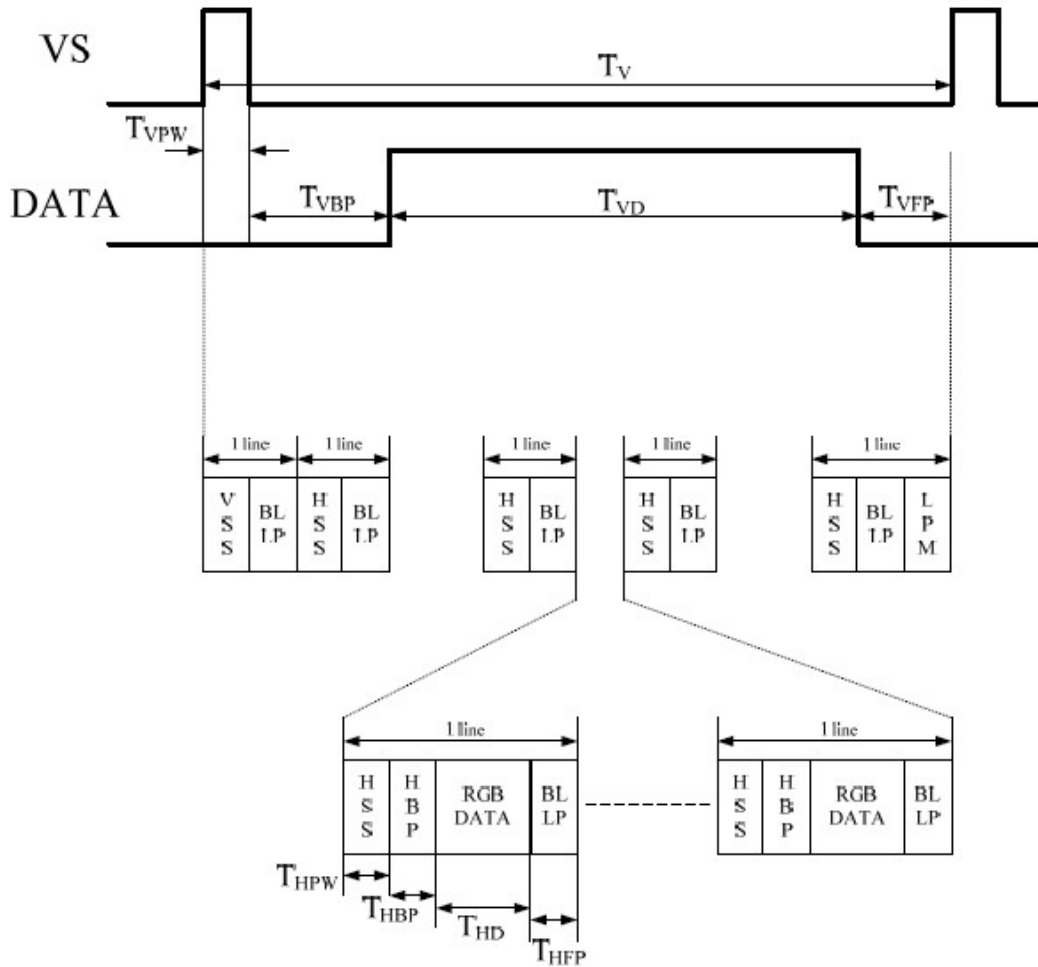
- (1) After Reset, => LP-11
- (2) After DSI-CLK_P/M lanes are leaving ULPM (LP-00) => LP-10 => LP-11 (LPM)



From ULPM to LPM

- (3) After DSI-CLK_P/M lanes are leaving HSCM (HS-0 or HS-1) => HS-0 => LP-11 (LPM)

9.5 Data Input Format for MIPI



10. Initial Code

Please consult our technical department for detail information.

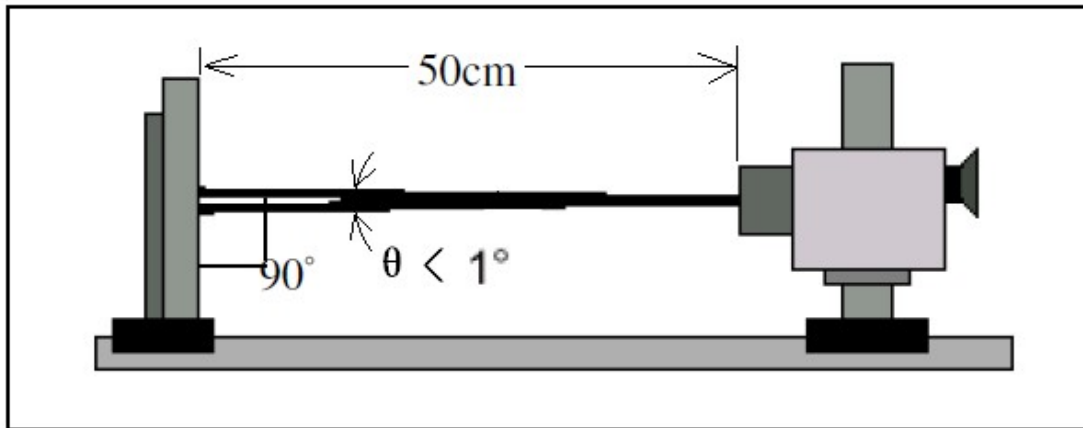
11. Electro-Optical Characteristics

Item	Symbol	Condition	Min	Typ	Max	Unit	Note
Response time	Tr+Tf	$\theta = 0^\circ$ $\phi = 0^\circ$ Ta=25°C	-	35	-	ms	4
Uniformity (Five point)	δ WHITE		-	80	-	%	7
Contrast ratio	Cr		-	900	-	-	3,5
Surface Luminance (w/o CTP)	Lv		-	500	-	-	3,7
Viewing angle range	θ	$\phi = 90^\circ$	80	85	-	deg	6
		$\phi = 270^\circ$	80	85	-	deg	
		$\phi = 0^\circ$	80	85	-	deg	
		$\phi = 180^\circ$	80	85	-	deg	
Color filter chromaticity (x, y)	R _x	$\theta = \phi = 0^\circ$	TBD	TBD	TBD	-	7
	R _y		TBD	TBD	TBD		
	G _x		TBD	TBD	TBD		
	G _y		TBD	TBD	TBD		
	B _x		TBD	TBD	TBD		
	B _y		TBD	TBD	TBD		
	W _x		TBD	TBD	TBD	-	-
	W _y		TBD	TBD	TBD	-	-
NTSC	%	$\theta = \phi = 0$	-	60	-	%	-

Note 1: Ambient temperature=25°C±2°C

Note 2: To be measured in the dark room with backlight unit.

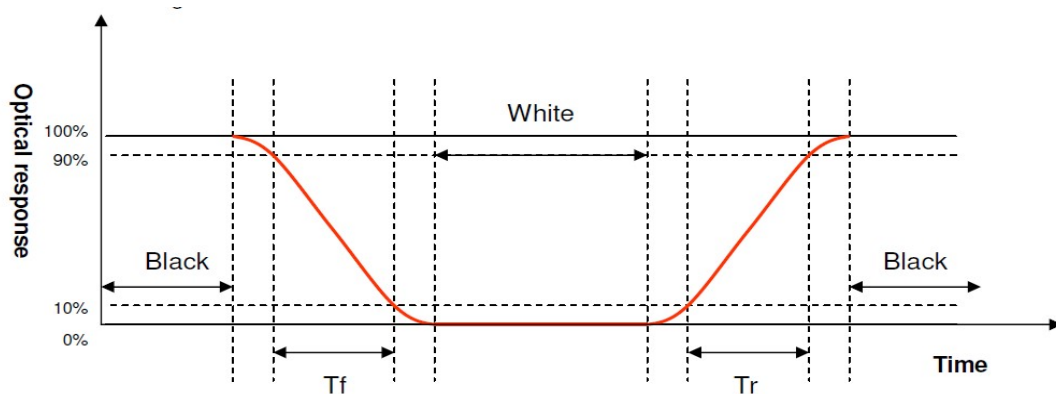
Note 3: To be measured at the center area of panel with a viewing cone of 1 by Topcon luminance meter BM-7A, after 10 minutes operation (module).



Note 4: Definition of response time:

The output signals of photo detector are measured when the input signals are changed from “black” to “white” (rising time) and from “white” to “black” (falling time), respectively. The response time is defined as the time interval between the 10% and 90% of amplitudes.

Refer to figure as below.



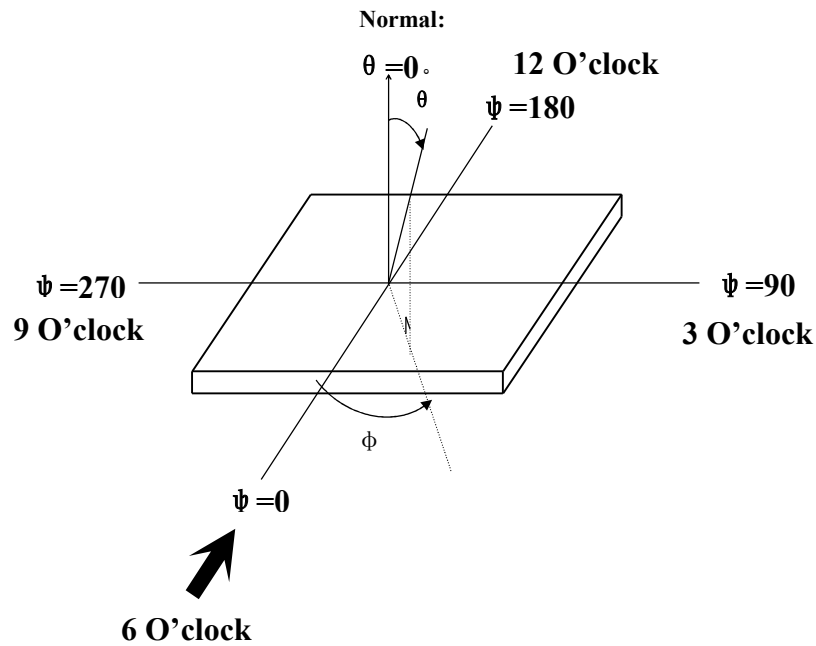
Note 5. Definition of contrast ratio:

Contrast ratio is calculated with the following formula:

$$\text{Contrast ratio (CR)} = \frac{\text{Photo detector output when LCD is at "White" state}}{\text{Photo detector output when LCD is at "Black" state}}$$

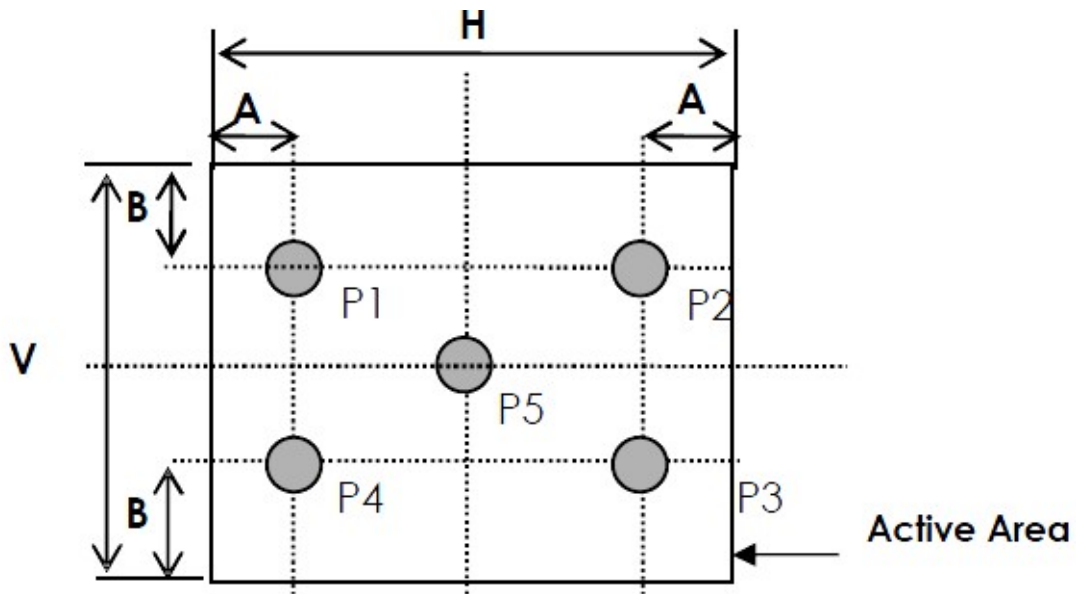
Note 6. Definition of viewing angle

Viewing angle is the angle at which the contrast ratio is greater than 10 for TFT module. The angles are determined for the horizontal or x axis and the vertical or y axis with respect to the z axis which is normal to the LCD surface.



Note 7. Surface luminance is the LCD surface from the surface with all pixels displaying white. Refer to figure as below.

Measuring method for Contrast ratio, surface luminance, Luminance uniformity, CIE (x, y) chromaticity



A : 5 mm B : 5 mm H,V : Active Area

Light spot size $\varnothing=7\text{mm}$, 500mm distance from the LCD surface to detector lens

measurement instrument is TOPCON's luminance meter BM-7A

Uniformity definition= [min of 5point/max of 5points]x100%

L_v = Surface Luminance with all white pixels (P5)

12. Reliability Test

This standard reliability test is done only for the first lot of MP products.

Customer and supplier must hold a discussion if other reliability test is requested by customer.

NO.	Test Item	Description	Test Condition
	High temperature storage	Endurance test applying the high storage temperature for a long time	80°C, 240 H
2	Low temperature storage	Endurance test applying the low storage temperature for a long time	-30°C, 240H
3	High temperature operation	Endurance test applying the electric stress under high temperature for a long time	70°C, 240H
4	Low temperature operation	Endurance test applying the electric stress under low temperature for a long time	-20°C, 240H
5	High temperature /humidity storage	Endurance test applying the high temperature and high humidity storage for a long time	60°C, 90% RH, 240H
6	Temperature Cycle (Non operation)	Endurance test applying the low and high temperature cycle -30°C ← → 25°C ← → 80°C 30min ← → 5min ← → 30min one cycle	-30°C/80°C, 100 cycles
7	ESD Test	To check the product operating capability after electrostatic environment.	Voltage: ± 6KV(contact discharge); ±10 KV(air discharge)
8	Drop Test (package)	Height: 100 cm, 1 corner, 3 edges, 6 surfaces	IEC60068-2-32:1990 GB/T2423.8—1995
9	Vibration test (Non-operation)	Frequency range: 10~55Hz, Stroke: 1.5mm Sweep: 10Hz~55Hz~10Hz 2 hours for each direction of X.Y.Z. (6 hours for total)(Package condition)	IEC60068-2-6:1982 GB/T2423.10—1995

13. Precautions for Operation and Storage

1. Precautions for Operation

(1) Since LCD panel made of glass, in order to prevent from glass broken or color tone change, please do not apply any mechanical shock or impact or excessive force to it when installing the LCD module.

(2) If LCD panel is broken and liquid crystal substance leaks out and contact your skin or clothes, please immediately wash it off by using soap and water.

(3) The polarizer on the LCD surface is soft and easily scratched. Please be careful when handling.

(4) If LCD surface becomes contaminated, please wipe it off gently by using moisten soft cloth with normal hexane, do not use acetone, ketone, ethanol, alcohol or water. If there is saliva or water on the LCD surface, please wipe it off immediately.

(5) When handling LCD module, please be sure that the body and the tools are properly grounded. And do not touch I/F pins with bare hands or contaminate I/F pins.

(6) Do not attempt to disassemble or process the LCD module.

(7) LCD module should be used under recommended operating conditions shown in chapter 6 and 7. Make sure that all conductive parts on the complete unit, where the LCD is integrated, are not floated.

(8) Response time will be extremely slower at lower temperature than at specified temperature and LCD will show different color when at higher temperature. The phenomenon will disappear when returning to specified condition.

(9) Foggy dew, moisture condensation or water droplets deposited on surface and contact terminals will cause polarizer stain or damage, the deteriorated display quality and electrochemical reaction then leads to the shorter life time and permanent damage to the module probably. Please pay attention to the environmental temperature and humidity.

2. Precautions for Storage

(1) Please store LCD module in a dark place, avoid exposure to sunlight, the light of fluorescent lamp or any ultraviolet ray.

(2) Keep the environment temperature at between 10°C and 35 °C and at normal humidity. Avoid high temperature, high humidity or temperature below 0°C.

(3) That keeps the LCD modules stored in the container shipped from supplier before using them is recommended.

3. Warranty period

14. Package Specification

TBD.

****Declaration: Products are guaranteed halogen-free and meet ROHS requirements.**